



LC86E4564

8-Bit Single-Chip Microcontroller

Preliminary

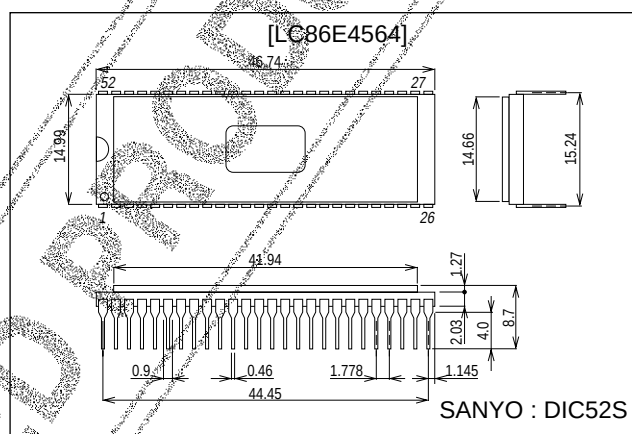
Overview

The LC86E4564 is a CMOS 8-bit single chip microcontroller with UVEPROM for the LC864500 series. This microcontroller has the same function and the pin assignment as for the LC864500 series mask ROM version, and the 64K-byte EPROM. The program data is rewritable. It is suitable for developing programs.

Package Dimensions

unit : mm

3225-DIC52S



Features

- (1) Option switching by EPROM data
The option function of the LC864500 series can be specified by the EPROM data.
The functions of the trial pieces can be evaluated using the mass production board.
- (2) Internal EPROM capacity : 65512 bytes (for program)
: 8192 × 12-bit (for character)
- (3) Internal RAM capacity : 256 bytes

Mask ROM version	EPROM capacity	RAM capacity
LC864532	32768 bytes	256 bytes
LC864528	28672 bytes	256 bytes
LC864524	24576 bytes	256 bytes
LC864520	20480 bytes	256 bytes
LC864516	16256 bytes	256 bytes
LC864512	12288 bytes	256 bytes
LC864508	8192 bytes	256 bytes

- (4) Operating voltage : 4.5 V to 5.5 V
- (5) Instruction cycle time : 1.0 μs to 366 μs
- (6) Operating temperature : +10°C to +40°C
- (7) The pin and the package compatible with the LC864500 series mask ROM devices
- (8) Applicable mask ROM version : LC864532, LC864528, LC864524, LC864520, LC864516, LC864512, LC864508
- (9) Factory shipment : DIC52S

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Usage Notes

When using, take notice of the followings.

(1) Differences between the LC86E4564 and the LC864500 series

Item	LC86E4564	LC864532/28/24/20/16/12/08
Operation after reset releasing	The option is specified by degrees until 3 ms after going to a 'H' level to the reset pin. The program is executed from 00H of the program counter.	The program is executed from 00H of the program counter immediately after going to a 'H' level to the reset pin.
Operating voltage range (V _{DD})	4.5 V to 6.0 V	2.5 V to 6.0 V
Operating temperature range (Topr)	+10 to +40°C	-30 to +70°C
Current drain	Refer to 'Electrical Characteristics' on the semiconductor news.	

The LC86E4564 uses the program memory area of 256 bytes from 0EF00H to 0FFFFH to select the options.

• The option types of the LC86E4564

Option types	Pins, Circuits	Contents of the option
Input/output form of input/output ports	Port 0	1. N-channel open drain output 2. CMOS output *1
		1. Pull-up MOS transistor provided 2. Pull-up MOS transistor not provided *2
	Port 1	1. Input : Programmable pull-up MOS transistor Output : N-channel open drain
		2. Input : Programmable pull-up MOS transistor Output : CMOS
Port 7 pull-up MOS transistor	Port 7	1. Input : No Programmable pull-up MOS transistor 2. Input : Programmable pull-up MOS transistor

*1) Specified in bit

*2) Specified in nibble unit. Pull-up MOS transistor is not provided in N-channel open drain output port.

(2) Option

The option data is written with the option specifying program "SU86K.EXE". The option data is linked to the program area by the linkage loader "L86K.EXE".

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(3) ROM space

The LC86E4564 and LC864500 series use the program memory area of 256 bytes from 0FF00H to 0FFFFH to select the options. The program memory capacity of the series is 65280 bytes addressed on 0000H to 0FEFFH.

Note that the capacity of the LC86E4564 user-available EPROM is 32768 bytes addressed on 0000H to 7FFFH, although the LC86E4564 has 65536-byte EPROM.

13FFFFH	Character generator ROM	Character generator ROM	Character generator ROM	Character generator ROM	Character generator ROM	Character generator ROM	Character generator ROM
0FFFFH	Option specified area 256 bytes	Option specified area 256 bytes	Option specified area 256 bytes	Option specified area 256 bytes	Option specified area 256 bytes	Option specified area 256 bytes	Option specified area 256 bytes
0FF00H							
0FEFFH							
0DFFFFH							
0BFFFFH							
09FFFFH							
07FFFFH							
05FFFFH							
04FFFFH							
03FFFFH	Program area 32K bytes	Program area 28K bytes	Program area 24K bytes	Program area 20K bytes	Program area 16K bytes	Program area 12K bytes	Program area 8K bytes
02FFFFH							
0000H							
	LC864532	LC864528	LC864524	LC864520	LC864516	LC864512	LC864508

Writing to EPROM

(1) Create programming data for LC86E4564

Programming data for EPROM of the LC86E4564 is required.

Debugged evaluation file (EVA file) must be converted to an INTEL-HEX formatted file (HEX file) with file converter program SU86K.EXE. The HEX file is used as the programming data for the LC86E4564.

(2) How to write data to EPROM

The LC86E4564 can be programmed by a general-purpose EPROM programmer with attachment W86EP4564D.

- Recommended EPROM programmer

Supplier	EPROM programmer
Advantest	R4945, R4944, R4943
Andou	AF-9704
AVAL	PKW-1100, PKW-3000
Minato Electronics	MODEL1890A

- "27010 (V_{p-p} = 12.5 V) Intel high-speed programming" mode should be adopted. The address must be set to "0 to 13FFFH" and a jumper (DASEC) must be set to 'OFF' at programming.

(3) How to use the data security function

"Data security" is the function reading to disable the EPROM data from being read out.

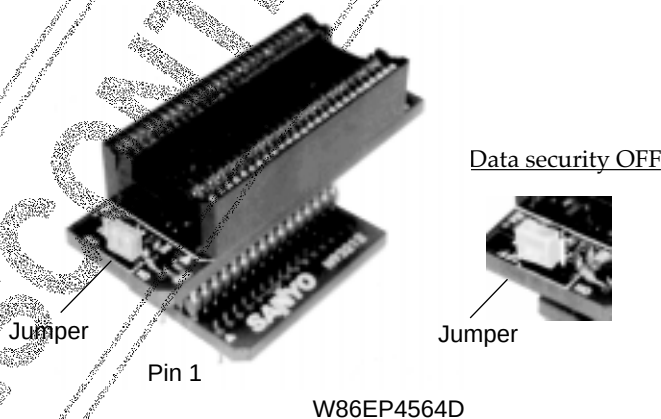
The following is the process in order to execute data security function.

1. Set the jumper of attachment 'ON'.
2. Program again. The EPROM programmer will display an error. The error means that the data security functions normally. It is not a trouble of the EPROM programmer or the LSI.

Notes

- Data security is not executed when the data of all addresses have 'FF' at sequence 2 above.
- Data security cannot be executed by programming the sequential operation "BLANK=>PROGRAM=>VERIFY" cannot be executed data security at procedure 2 above.
- Set the jumper to 'OFF' after executing data security.

Data security



(4) How to eliminate

The programming data can be erased by using the EPROM eraser.

(5) Shielding

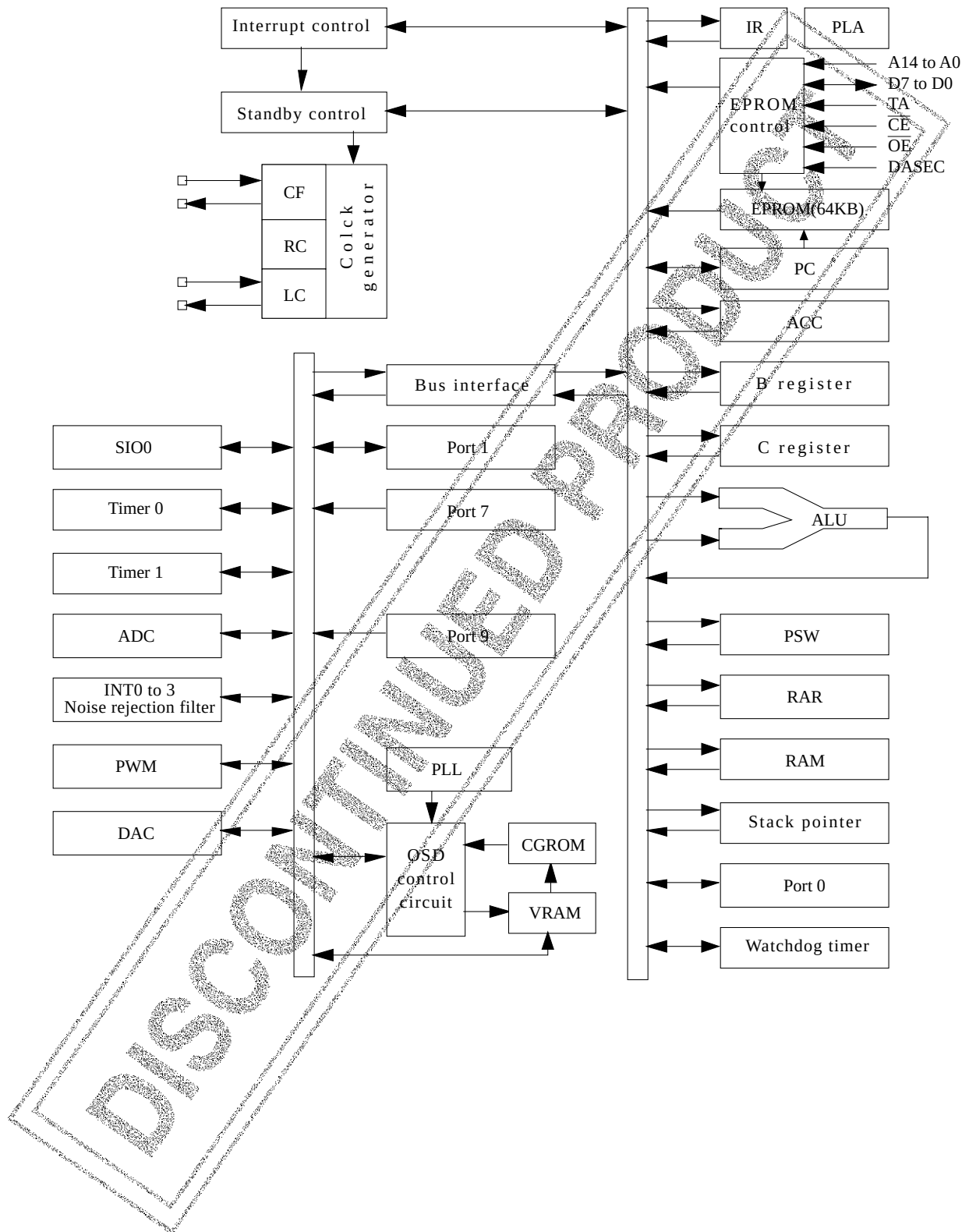
Because the UVEPROM (ultraviolet erasable programmable ROM) is incorporated in LC86E4564, put the seal on the window in use.

Pin Assignment

P10/S00	1	52	P07
P11/SI0/SB0	2	51	P06
P12/SCK0	3	50	P05
P13	4	49	P04
P14	5	48	P03
P15	6	47	P02
P16	7	46	P01
P17/PWM	8	45	P00
DVSS	9	44	P73/INT3/T0IN
CF1	10	43	P72/INT2/T0IN
CF2	11	42	P71/INT1
DVDD	12	41	P70/INT0
P90/AN0	13	40	PWM9
P91/AN1	14	39	PWM8
P92/AN2	15	38	PWM7
P93/AN3	16	37	PWM6
RES	17	36	PWM5
LC1	18	35	PWM4
LC2	19	34	PWM3
FILT	20	33	PWM2
AVDD	21	32	PWM1
AVSS	22	31	PWM0
DA0	23	30	BL
DA1	24	29	B
VS	25	28	G
HS	26	27	R

Top view

System Block Diagram



Pin Description

- Port option can be specified by bit units except the pull-up resistor selection of port 0.

Pin Description Table

Pin name	Pin No.	I/O	Function description	Option	PROM mode
DVSS	9	—	Negative power supply for digital circuit		
CF1	10	I	Input for ceramic resonator		
CF2	11	O	Output for ceramic resonator		
DVDD	12	—	Positive power supply for digital circuit		
RES	17	I	Reset		
LC1	18	I	LC oscillation circuit input		
LC2	19	O	LC oscillation circuit output		
FILT	20	O	Filter for PLL		
AVDD	21	—	Positive power supply for analog circuit		
AVSS	22	—	Negative power supply for analog circuit		
DA0	23	I/O	DA0 output / General I/O port		
DA1	24	I/O	DA1 output / General I/O port		
VS	25	I	Vertical synchronization signal input		
HS	26	I	Horizontal synchronization signal input		
R	27	O	Red (R) output of RGB image output		A4 (*1)
G	28	O	Green (G) output of RGB image output		A5 (*1)
B	29	O	Blue (B) output of RGB image output		A6 (*1)
BL	30	O	Fast blanking control signal Switch TV image signal and OSD image signal		A7 (*1)
PWM0 to PWM9	31 to 40	O	PWM0 to 9 output 15 V withstand		PWM 0 to 8 : A8 to A16 (*1) PWM 9 : "L" fixed
Port 0 P00 to P07	45 to 52	I/O	8-bit Input / output port	Pull-up resistor Provided/not provided (in bit units) Output Format CMOS/Nch-OD (in bit units)	
			Input / output can be specified in nibble units HOLD release input Interrupt input		
Port 1 P10 to P17	1 to 8	I/O	8-bit Input/output port	Output format CMOS/Nch-OD (in bit units)	D0 to D7 (*2)
			Input/output can be specified in bit units. Other function		
			P10 SIO0 data output P11 SIO0 data input / bus input / output P12 SIO0 clock input / output P17 Timer 1 (PWM) output		

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Pin name	Pin No.	I/O	Function Description				Option	PROM mode			
Port 7	41 42 to 44	I/O I	4-bit input port Other function				Pull-up resistor provided/ not provided (in bit units)	P70 : VPP (*3) P71 : DASEC (*4) P72 : OE (*5) P73 : CE (*6)			
P70			P70 INT0 input/HOLD release input/ Nch-transistor output for watchdog timer								
P71 to P73			P71 INT1 input/HOLD release input P72 INT2 input/timer 0 event input P73 INT3 input (noise rejection filter attached input/timer 0 event input) Interrupt receiver format vector address								
			Rise	Fall	Rise/Fall	H level			L level	Vector	
			INT0	enable	enable	disable			enable	enable	03H
			INT1	enable	enable	disable			enable	enable	0BH
	INT2	enable	enable	enable	disable	disable	13H				
	INT3	enable	enable	enable	disable	disable	1BH				
Port 9	13 to 16	I	4-bit input port Other function					A0 to A3 (*1)			
P90 to P93			A/D converter input port (4 lines)								

*1 An → Address input

*2 Data I/O

*3 Power for programming

*4 Memory select input/output for data security

*5 Output Enable input

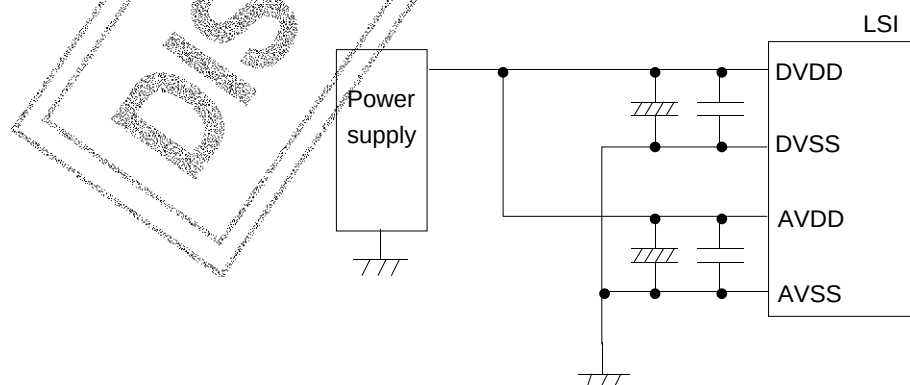
*6 Chip Enable input

• All of port options except the pull-up resistor option of Port 0 can be specified in a bit unit.

• Port status in reset

Terminal	I/O	Pull-up resistor status at selecting pull-up option
Port 0	Input	Pull-up resistor OFF, ON after reset release
Port 1	Input	Programmable pull-up resistor OFF
Port 7	Input	Fixed pull-up resistor provided

* AVDD and AVSS are the power supply terminals for the analog operation block. DVDD and DVSS are the power supply terminals for the digital operation block. Connect as shown in the following figure to reduce the noise influence.



Specifications

1. Absolute Maximum Ratings at Ta = 25°C, V_{SS} = 0 V

Parameter		Symbol	Pins	Conditions	V _{DD} [V]	Ratings			Unit
						min	typ	max	
Supply voltage		V _{DDmax}	DVDD, AVDD	DVDD = AVDD		−0.3		+7.0	V
Input voltage		V _I (1)	• P71, 72, 73 • Port 9 • $\overline{\text{RES}}$, $\overline{\text{HS}}$, $\overline{\text{VS}}$			−0.3		V _{DD} +0.3	
Output voltage		V _O (1)	R, G, B, BL, FILT			−0.3		V _{DD} +0.3	
		V _O (2)	PWM0 to PWM9			−0.3		+15	
Input/output voltage		V _{IO} (1)	Ports 0, 1, P70 DA0, 1			−0.3		V _{DD} +0.3	
High-level output current	Peak output current	I _{OPH} (1)	Ports 0, 1	• Pull-up MOS transistor output • At each pin		−2			mA
		I _{OPH} (2)	Ports 0, 1 DA0, 1	• CMOS output • At each pin		−4			
		I _{OPH} (3)	R, G, B, BL	• CMOS output • At each pin		−5			
	Total output current	ΣI _{OA} H(1)	Port 1	The total of all pins		−10			
		ΣI _{OA} H(2)	Port 0	The total of all pins		−10			
		ΣI _{OA} H(3)	R, G, B, BL	The total of all pins		−15			
Low-level output current	Peak output current	I _{OPL} (1)	Ports 0, 1 DA0, 1	At each pin				20	
		I _{OPL} (2)	P70	At each pin				30	
		I _{OPL} (3)	• R, G, B, BL • PWM0 to PWM9	At each pin				5	
	Total output current	ΣI _{OAL} (1)	Port 0	The total of all pins				40	
		ΣI _{OAL} (2)	Port 1, P70	The total of all pins				40	
		ΣI _{OAL} (3)	R, G, B, BL	The total of all pins				15	
		ΣI _{OAL} (4)	PWM0 to PWM9	The total of all pins				30	
Maximum power dissipation		P _{d max}	DIC52S	T _a = +10 to +40°C				600	mW
Operating temperature range		T _{opr}				10		+40	°C
Storage temperature range		T _{stg}				−55		+150	

* DV_{SS} and AV_{SS} must be supplied the same voltage, V_{SS}.
DV_{DD} and AV_{DD} must be supplied the same voltage, V_{DD}.

V_{SS} = DV_{SS} = AV_{SS}
V_{DD} = DV_{DD} = AV_{DD}

2. Recommended Operating Range at $T_a = +10^{\circ}\text{C}$ to $+40^{\circ}\text{C}$, $V_{SS} = 0\text{ V}$

Parameter	Symbol	Pins	Conditions	Ratings			Unit	
				V _{DD} [V]	min	typ		max
Operating supply voltage range	V _{DD}	DVDD, AVDD	0.98 μs ≤ tCYC tCYC ≤ 1.02 μs		4.5		5.5	V
Hold voltage	V _{HD}	DVDD, AVDD	RAMs and the registers hold data at HOLD mode.		2.0		5.5	
Input high voltage	V _{IH} (1)	Port 0 (Schmitt)	Output disable	4.5 to 5.5	0.6V _{DD}		V _{DD}	
	V _{IH} (2)	• Port 1 (Schmitt) • P72, 73 • HS, VS	Output disable	4.5 to 5.5	0.75V _{DD}		V _{DD}	
	V _{IH} (3)	• P70 port input / interrupt • P71 • RES (Schmitt)	Output N-channel transistor OFF	4.5 to 5.5	0.75V _{DD}		V _{DD}	
	V _{IH} (4)	P70 Watchdog timer input	Output N-channel transistor OFF	4.5 to 5.5	V _{DD} −0.5		V _{DD}	
	V _{IH} (5)	Port 9 DA0, 1 port input		4.5 to 5.5	0.7V _{DD}		V _{DD}	
Input low voltage	V _{IL} (1)	Port 0 (Schmitt)	Output disable	4.5 to 5.5	V _{SS}		0.2V _{DD}	
	V _{IL} (2)	• Port 1 (Schmitt) • P72, 73 • HS, VS • Port 9	Output disable	4.5 to 5.5	V _{SS}		0.25V _{DD}	
	V _{IL} (3)	• P70 port input / interrupt • P71 • RES (Schmitt)	N-channel transistor OFF	4.5 to 5.5	V _{SS}		0.25V _{DD}	
	V _{IL} (4)	P70 Watchdog timer input	N-channel transistor OFF	4.5 to 5.5	V _{SS}		0.6V _{DD}	
	V _{IL} (5)	Port 9 DA0, 1 port input		4.5 to 5.5	V _{SS}		0.3V _{DD}	
Operation cycle time	tCYC(1)		OSD function	4.5 to 5.5	0.98	1	1.02	μs
	tCYC(2)		Except OSD function	4.5 to 5.5	0.98		30	
Oscillation frequency range (Note 1)	FmCF	CF1, CF2	12 MHz (ceramic resonator oscillation) Refer to Figure 1.	4.5 to 5.5	11.76	12	12.24	MHz
	FmLC	LC1, LC2	14.11 MHz (LC oscillation) Refer to Figure 2.	4.5 to 5.5	14.11			
	FmRC		RC oscillation	4.5 to 5.5	0.4	0.8	3.0	
Oscillation stable time period (Note 2)	tmsCF	CF1, CF2	12 MHz (ceramic resonator oscillation) Refer to Figure 3.	4.5 to 5.5		0.02	0.2	ms

Note 1: Refer to Table 1 and Table 2 for oscillation constant.

Note 2: The oscillation stable time period refers to the time it takes to oscillate stably after the following conditions.

1. Applying the first supply voltage.
2. Release of the HOLD mode.
3. Release of the stopping of the main-clock oscillation.

3. Electrical Characteristics at Ta= +10°C to +40°C, V_{SS} = 0 V

Parameter	Symbol	Pins	Conditions	V _{DD} [V]	Ratings			Unit
					min	typ	max	
Input high-level current	I _{IH} (1)	• Port 1 DA0, 1 • Port 0 without pull-up MOS transistor	• Output disable • Pull-up MOS transistor OFF • V _{IN} = V _{DD} (including the off-leak current of the output transistor)	4.5 to 5.5			1	μA
	I _{IH} (2)	• Port 7 without pull-up MOS transistor • Port 9 • $\overline{\text{RES}}$ • $\overline{\text{HS}}$, $\overline{\text{VS}}$	V _{IN} = V _{DD}	4.5 to 5.5			1	
Input low-level current	I _{IL} (1)	• Port 1 DA0, 1 • Port 0 without pull-up MOS transistor	• Output disable • Pull-up MOS transistor OFF • V _{IN} = V _{SS} (including the off-leak current of the output transistor)	4.5 to 5.5	-1			
	I _{IL} (2)	• Port 7 without pull-up MOS transistor • Port 9	V _{IN} = V _{SS}	4.5 to 5.5	-1			
	I _{IL} (3)	• $\overline{\text{RES}}$ • $\overline{\text{HS}}$, $\overline{\text{VS}}$	V _{IN} = V _{SS}	4.5 to 5.5	-1			
Output high-level voltage	V _{OH} (1)	CMOS output of ports 0, 1 DA0, 1	I _{OH} = -1.0 mA	4.5 to 5.5	V _{DD} -1			V
	V _{OH} (2)	R, G, B, BL	I _{OH} = -0.1 mA	4.5 to 5.5	V _{DD} -0.5			
Output low-level voltage	V _{OL} (1)	Ports 0, 1	I _{OL} = 10 mA	4.5 to 5.5			1.5	
	V _{OL} (2)	Ports 0, 1 DA0, 1	• I _{OL} = 1.6 mA • The total current of the ports 0, 1 is 40 mA or less.	4.5 to 5.5			0.4	
	V _{OL} (3)	• R, G, B, BL • PWM0 to PWM9	• I _{OL} = 3.0 mA • The current of any unmeasured pin is 3 mA or less.	4.5 to 5.5			0.4	
	V _{OL} (4)	P70	I _{OL} = 1 mA	4.5 to 5.5			0.4	
Pull-up MOS transistor resistance	R _{pu}	• Ports 0, 1 • Port 7	V _{OH} = 0.9V _{DD}	4.5 to 5.5	13	38	80	kΩ
Output off-leakage current	I _{OFF}	PWM0 to PWM9	V _{OUT} = 13.5 V	4.5 to 5.5			5	μA
Hysteresis voltage	V _{HIS}	• Ports 0, 1 • Port 7 • $\overline{\text{RES}}$ • $\overline{\text{HS}}$, $\overline{\text{VS}}$	Output disable	4.5 to 5.5		0.1V _{DD}		V
Pin capacitance	CP	All pins	• f = 1 MHz • Unmeasured input pins are set to V _{SS} level. • Ta = 25°C	4.5 to 5.5		10		pF

4. Serial Input/Output Characteristics at $T_a = +10^{\circ}\text{C}$ to $+40^{\circ}\text{C}$, $V_{SS} = 0\text{ V}$

Parameter			Symbol	Pins	Conditions	V _{DD} [V]	Ratings			Unit
							min	typ	max	
Serial clock	Input clock	Cycle	tCKCY(1)	•SCK0 •SCLK0	Refer to Figure 5.	4.5 to 5.5	2			tCYC
		Low-level pulse width	tCKL(1)			4.5 to 5.5	1			
		High-level pulse width	tCKH(1)			4.5 to 5.5	1			
	Output clock	Cycle	tCKCY(2)	•SCK0 •SCLK0	•Use a pull-up resistor (1 kΩ) during open drain output •Refer to Figure 5.	4.5 to 5.5	2			
		Low-level pulse width	tCKL(2)			4.5 to 5.5		1/2tCKCY		
		High-level pulse width	tCKH(2)			4.5 to 5.5		1/2tCKCY		
Serial input	Data setup time	tICK	SI0	•Data setup to SCK0 rising •Data hold from SCK0 rising •Refer to Figure 5.	4.5 to 5.5	0.1			μs	
	Data hold time	tCKI			4.5 to 5.5	0.1				
Serial output	Output delay time (External serial clock)	tCKO(1)	SO0	•Use a pull-up resistor (1 kΩ) during open drain output. •Data setup to SCK0 falling •Data hold from SCK0 falling •Refer to Figure 5.	4.5 to 5.5			7/12tCYC +0.2	μs	
	Output delay time (Internal serial clock)	tCKO(2)			4.5 to 5.5			1/3tCYC +0.2		

5. Pulse Input Conditions at $T_a = +10^{\circ}\text{C}$ to $+40^{\circ}\text{C}$, $V_{SS} = 0\text{ V}$

Parameter	Symbol	Pins	Conditions	Ratings			Unit
				V_{DD} [V]	min	typ	max
High/low level pulse width	tPIH(1) tPIL(1)	•INT0, INT1 •INT2/T0IN	• Interrupt acceptable • Timer 0 pulse countable	4.5 to 5.5	1		tCYC
	tPIH(2) tPIL(2)	INT3/T0IN (The noise rejection clock is set to 1/1)	• Interrupt acceptable • Timer 0 pulse countable	4.5 to 5.5	2		
	tPIH(3) tPIL(3)	INT3/T0IN (The noise rejection clock is set to 1/16)	• Interrupt acceptable • Timer 0 pulse countable	4.5 to 5.5	32		
	tPIL(4)	RES	Reset acceptable	4.5 to 5.5	200		μs
	tPIH(5) tPIL(5)	HS, VS	Display position controllable Each active edge of HS, VS must be more than 1tCYC. Refer to Figure 7.	4.5 to 5.5	10		tCYC
Rise/fall time	tTHL tTLH	HS	Refer to Figure 7	4.5 to 5.5			500 ns
Horizontal pull-in range	FH	HS	The monitor point in Figure 10 is $1/2 V_{DD}$.	4.5 to 5.5	15.23	15.73	16.23 kHz

6. A/D Converter Characteristics at $T_a = +10^{\circ}\text{C}$ to $+40^{\circ}\text{C}$, $V_{SS} = 0\text{ V}$

Parameter	Symbol	Pins	Conditions	Ratings			Unit
				V_{DD} [V]	min	typ	max
Resolution	N			4.5 to 5.5		4	bit
Absolute precision	ET		Note 3	4.5 to 5.5		$\pm 1/4$	$\pm 1/2$ LSB
Conversion time	tCAD	From Vref selection to when the result is produced	1 bit conversion time = 2tCYC	4.5 to 5.5			1.96 μs
Reference current	I _{REF}		(Regulate the ladder resistor)	4.5 to 5.5		1.0	2.0 mA
Analog input voltage range	V _{AIN}	AN0 to AN3		4.5 to 5.5	V_{SS}		V_{DD} V
Analog port input current	I _{AINH}		$V_{AIN} = V_{DD}$	4.5 to 5.5			1 μA
	I _{AINL}		$V_{AIN} = V_{SS}$	4.5 to 5.5	-1		

Note 3: Absolute precision excepts quantizing error ($\pm 1/2$ LSB).

7. D/A Converter Characteristics at Ta = +10°C to +40°C, V_{SS} = 0 V

Parameter	Symbol	Pins	Conditions	Ratings			Unit
				V _{DD} [V]	min	typ	max
Resolution	NDA			4.5 to 5.5		7	bit
Absolute precision	ETDA		7 bits mode (Note 4)	4.5 to 5.5		±2.0	LSB
Settling time	tSDA		(Note 5)	4.5 to 5.5		1.0	μs
Analog input voltage range	V _{AOUT}	DA0 to DA1		4.5 to 5.5	V _{SS}		V _{DD}
Output register	RODA		(Note 6)	4.5 to 5.5		8	kΩ

Note 4 : Absolute precision excepts quantizing error (±1/2 LSB).

Note 5 : Settling time refers to the time from when the DA conversion instruction is executed to when the analog voltage output corresponding to the digital on the specific port is generated.

Note 6 : DA data = 80H

8. Current Drain Characteristics at Ta = +10°C to +40°C, V_{SS} = 0 V

Parameter	Symbol	Pins	Conditions	Ratings				Unit
				V _{DD} [V]	min	typ	max	
Current drain during basic operation (Note 7)	I _{DDOP} (1)	DV _{DD} , AV _{DD}	- FmCF = 12 MHz for ceramic resonator oscillation - FmLC = 14.11 MHz for LC oscillation - System clock: CF oscillation - Internal RC oscillation stops	4.5 to 5.5		21	32	mA
Current drain in HALT mode (Note 7)	I _{DDHALT} (1)	DV _{DD} , AV _{DD}	- HALT mode - FmCF = 12 MHz for ceramic resonator oscillation - FmLC = 0 Hz (when oscillation stops) - System clock : CF oscillation - Internal RC oscillation stops.	4.5 to 5.5		5	10	mA
	I _{DDHALT} (2)	DV _{DD} , AV _{DD}	- HALT mode - FmCF = 0 MHz (when oscillation stops) - FmLC = 0 Hz (when oscillation stops) - System clock : Internal RC	4.5 to 5.5		400	800	μA
Current drain in HOLD mode (Note 7)	I _{DDHOLD} (1)	DV _{DD} , AV _{DD}	- HOLD mode - All oscillation stop.	4.5 to 5.5		0.05	20	μA
	I _{DDHOLD} (2)							

Note 7 : The currents to the output transistors and the pull-up MOS transistors are ignored.

Oscillation type	Supplier	Oscillator	C1	C2
12 MHz ceramic resonator oscillation	Murata	CSA12.0MTZ	33 pF	33 pF
		CST12.0MTW	on chip	
	Kyocera	KBR-12.0M	47 pF	47 pF

* Both C1 and C2 must use K rank ($\pm 10\%$) and SL characteristics.

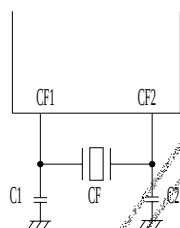
Table 1. Ceramic Resonator Oscillation Guaranteed Constants (Main clock)

Oscillation type	L	C3	C4
14.11 MHz LC oscillation	4.7 μ H	33 pF	45 pF (Trimmer)
	4.7 μ H $\pm 10\%$ (Variable)	33 pF	33 pF

* See Figures 11 and 12 for the LC oscillation frequency characteristics.

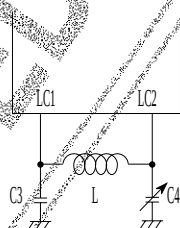
Table 2. LC oscillation Guaranteed Constants (OSD clock)

- (Notes)
- Since the circuit pattern affects the oscillation frequency, place the oscillation-related parts as close to the oscillation pins as possible with the shortest possible pattern length.
 - If you use other oscillators herein, we provide no guarantee for the characteristics.
 - Adjust the voltage of monitor point in Figure 10 to $1/2 V_{DD} \pm 10\%$ by the LC oscillation constant 'L' or 'C' to lock the PLL circuit.



main clock

Figure 1 Ceramic resonator oscillation



OSD clock

Figure 2 LC resonator oscillation

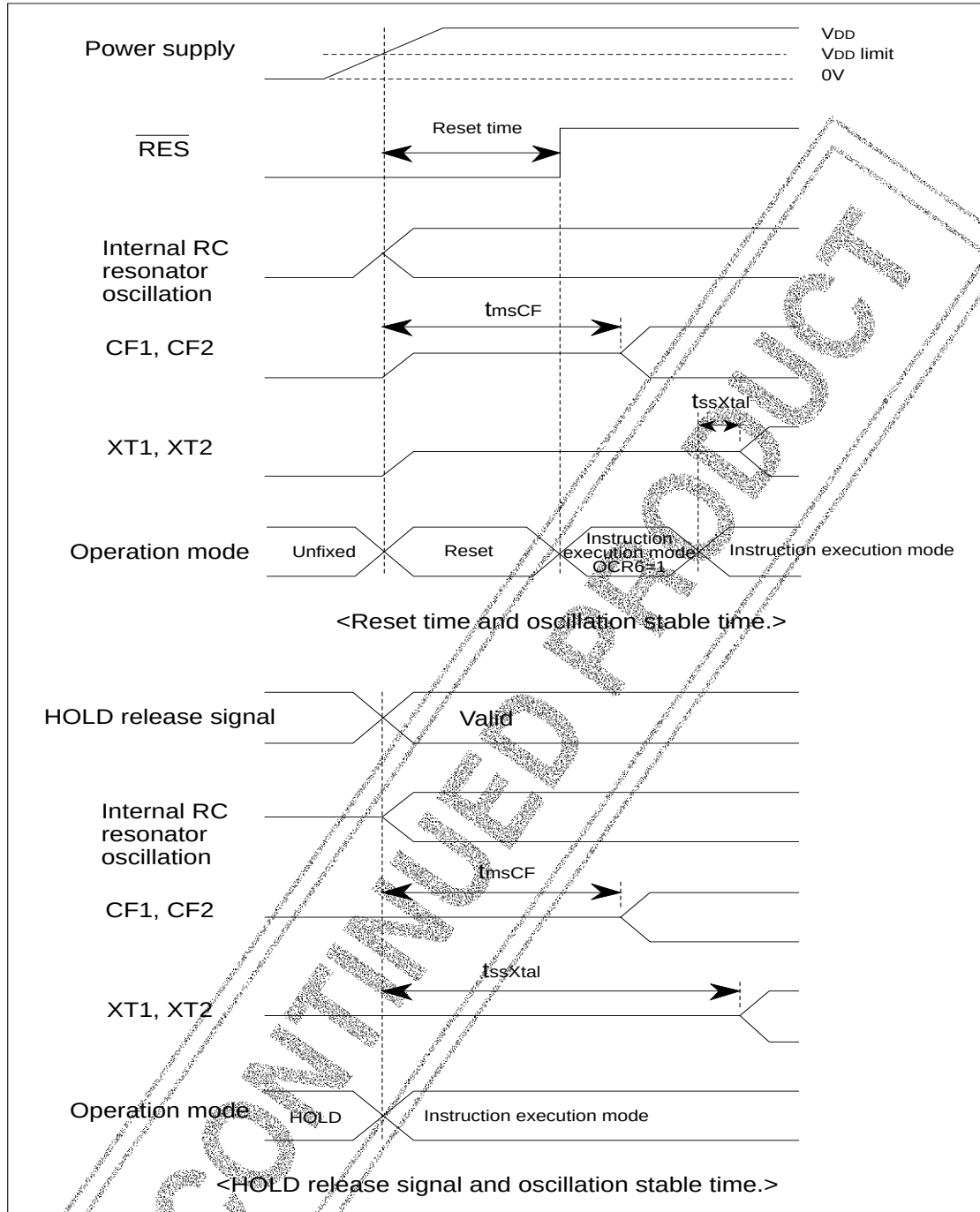
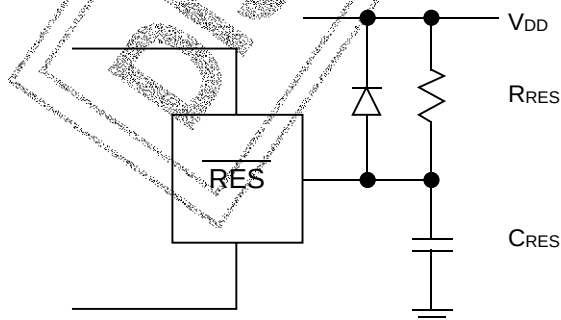


Figure 3 Oscillation Stable Time



(Note) Set the values of C_{RES} , R_{RES} so that the reset time is 200 μs or longer.

Figure 4 Reset Circuit

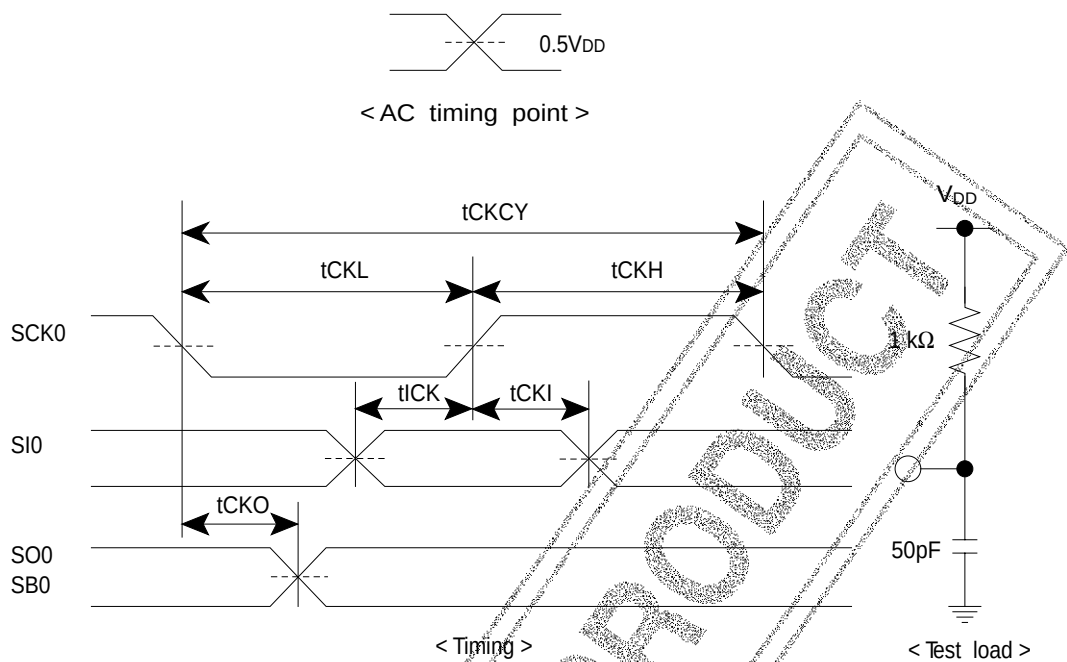


Figure 5 Serial Input/output Test Condition

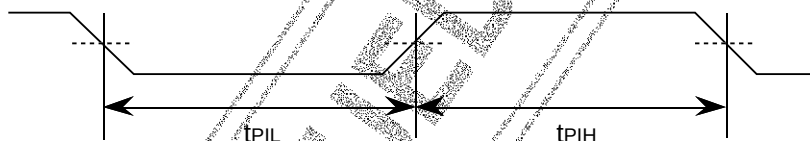


Figure 6 Pulse Input Timing Condition - 1

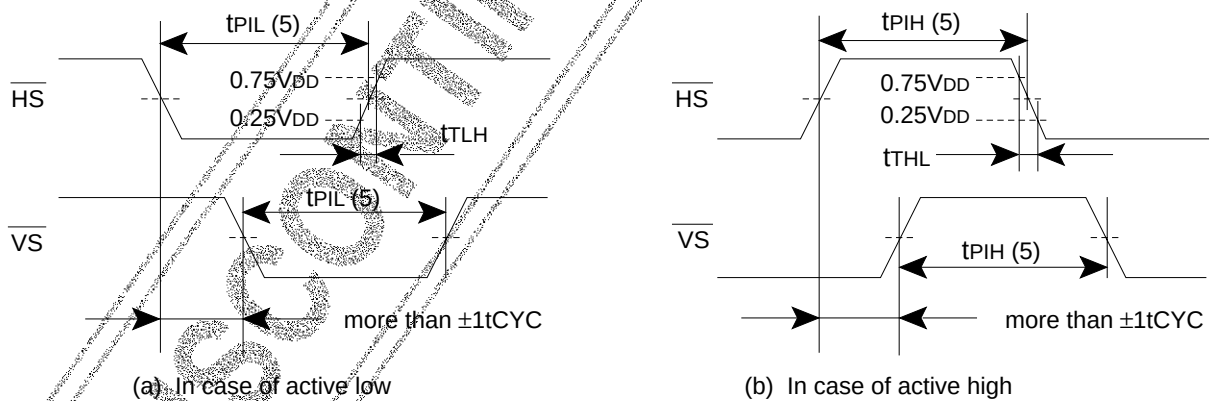


Figure 7 Pulse Input Timing Condition - 2

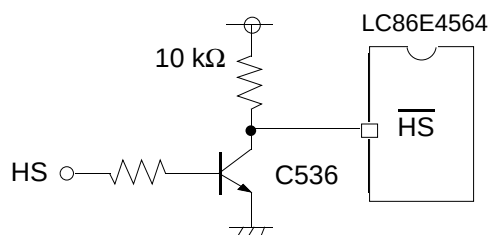


Figure 8 Recommended Interface Circuit

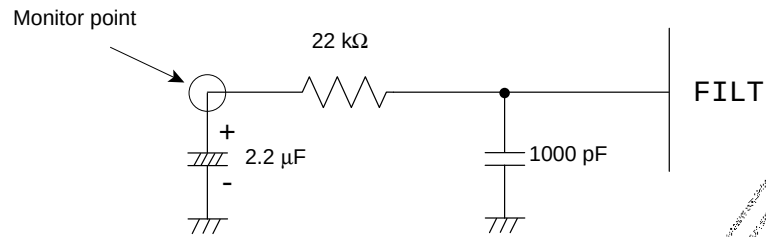


Figure 10 FILT Recommended Circuit

(Note) • Place the parts connected FILT terminal as close to the FILT as possible with the shortest pattern length on the board.

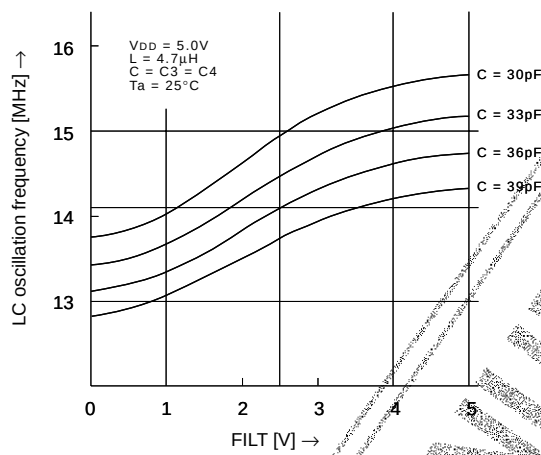


Figure 11 FILT-LC Oscillation Frequency (1)

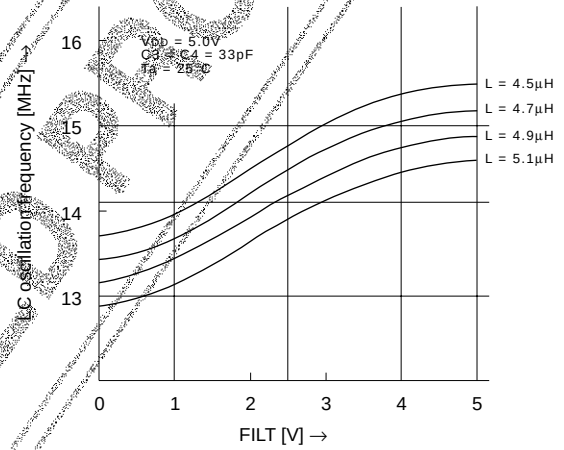
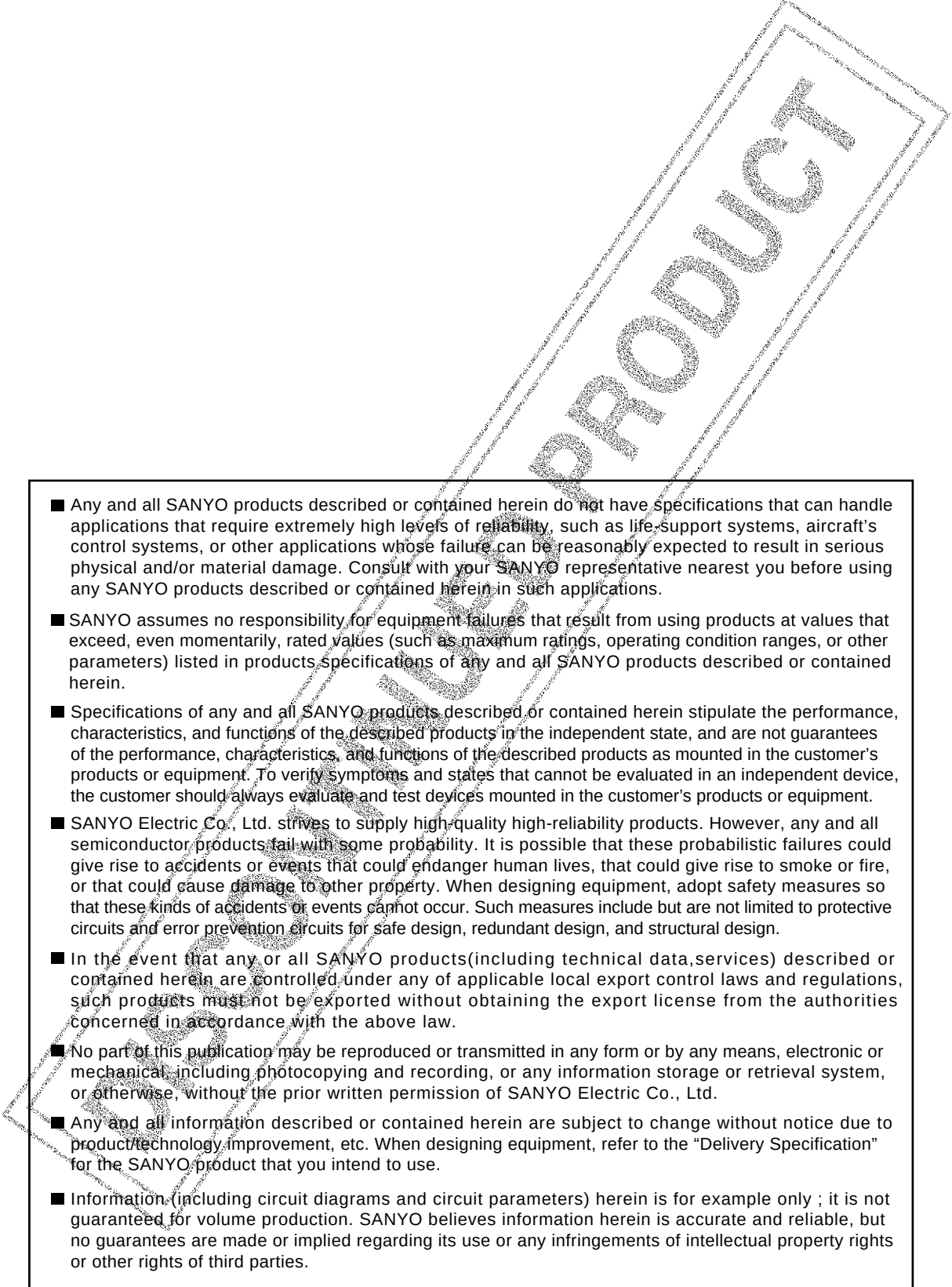


Figure 12 FILT-LC Oscillation Frequency (2)

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